## Development of Heavy Chalcogen-Embedded U-Shaped Heteroacenes Having Bilayer Self-Organization Capability

(<sup>1</sup>Grad. Sch. Eng., Kyushu Univ. <sup>2</sup>IFRC, Kyushu Univ.)  $\bigcirc$  Tatsuya Mori,<sup>1,2</sup> Takuma Yasuda<sup>1,2</sup>

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Controlling the supramolecular assemblies of  $\pi$ -conjugated molecules is essential to achieve excellent functions such as charge carrier transport. One needs to carefully consider both  $\pi$ -cores and heteroatoms to fully exploit the material properties. Heteroatom-containing fused aromatic  $\pi$ -scaffold, referred to as heteroacenes, have been actively studied for high-performance organic semiconductors because their highly ordered molecular packing in the solid states maximizes the intermolecular electronic couplings to facilitate the charge transport. So far, most of the heteroacene-based materials showing excellent semiconducting properties adopted the linear-shaped  $\pi$ -cores with sulfur atoms. However, there are countless combinations of available  $\pi$ -cores and heteroatoms, offering opportunities to develop novel materials endowed with attractive properties.

In this work, we developed a new series of U-shaped heteroacenes featuring unconventional "U" geometric configuration embedded with chalcogen atoms (sulfur, selenium, and tellurium).<sup>1,2</sup> The incorporation of heavier chalcogen atoms instead of sulfur effectively altered not only the basic optoelectronic properties but also the self-organization behaviors. Notably, U-shaped heteroacenes were found to form bilayer lamellar assemblies with a head-to-head arrangement, which is stabilized by the multiple intermolecular chalcogen interactions. High solvent solubility and crystallinity of U-shaped heteroacenes allowed us to apply them for a facile solution-based thin-film fabrication. Consequently, thin-film organic transistors based on selenium-embedded heteroacene exhibited high hole mobilities of up to  $3.8 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ . This work provided the advanced molecular design based on the U-shaped molecular configuration and strategic chalcogen substitution.<sup>1,2</sup>



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2) T. Mori, T. Oyama, H. Komiyama, T. Yasuda, J. Mater. Chem. C 2017, 5, 5872.